

**TC74VHCT573AF, TC74VHCT573AFW, TC74VHCT573AFT**

**OCTAL D-TYPE LATCH WITH 3-STATE OUTPUT**

The TC74VHCT573A is an advanced high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input ( $\overline{OE}$ ).

When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

The input voltage are compatible with TTL output voltage.

This device may be used as a level converter for interfacing 3.3V to 5V system.

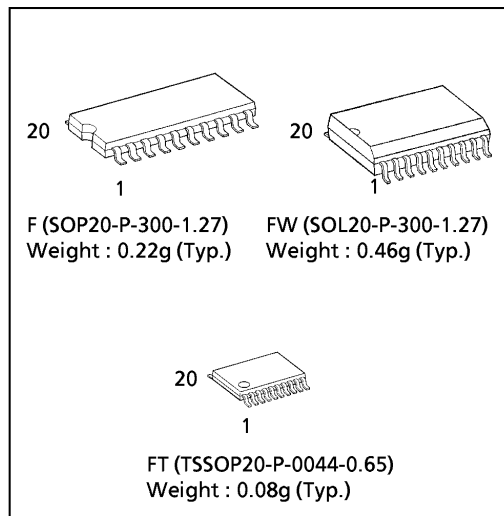
Input protection and output circuit ensure that 0 to 5.5V can be applied to the input and output\*1 pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

\*1: output in off-state

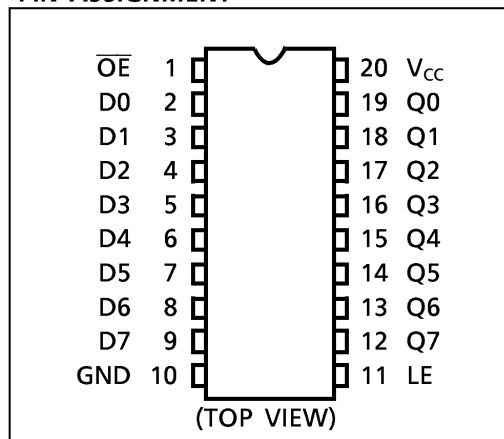
**FEATURES :**

- High Speed..... $t_{pd} = 7.7ns$ (typ.) at  $V_{CC} = 5V$
- Low Power Dissipation..... $I_{CC} = 4\mu A$ (Max.) at  $T_a = 25^\circ C$
- Compatible with TTL outputs.... $V_{IL} = 0.8V$  (Max.)  
 $V_{IH} = 2.0V$  (Min.)
- Power Down Protection is provided on all inputs and outputs.
- Balanced Propagation Delays..... $t_{pLH} \approx t_{pHL}$
- Low Noise ..... $V_{OLP} = 1.6V$  (Max.)
- Pin and Function Compatible with the 74 series (74AC / HC / F / ALS / LS etc.) 573 type.

(Note) The JEDEC SOP (FW) is not available in Japan.



**PIN ASSIGNMENT**

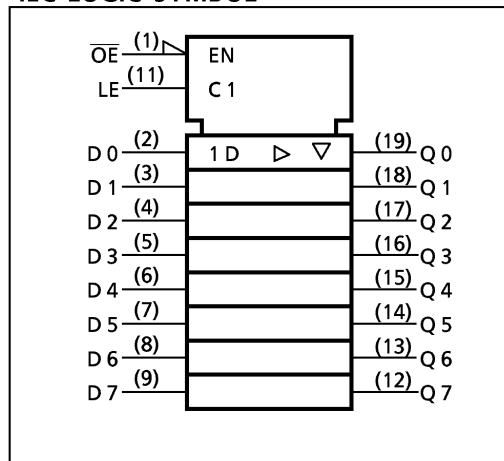


**TRUTH TABLE**

INPUTS			OUTPUT
$\overline{OE}$	LE	D	
H	X	X	Z
L	L	X	$Q_n$
L	H	L	L
L	H	H	H

X : Don't Care  
 Z : High Impedance  
 $Q_n$  : Q outputs are latched at the time when the LE input is taken to a low logic level.

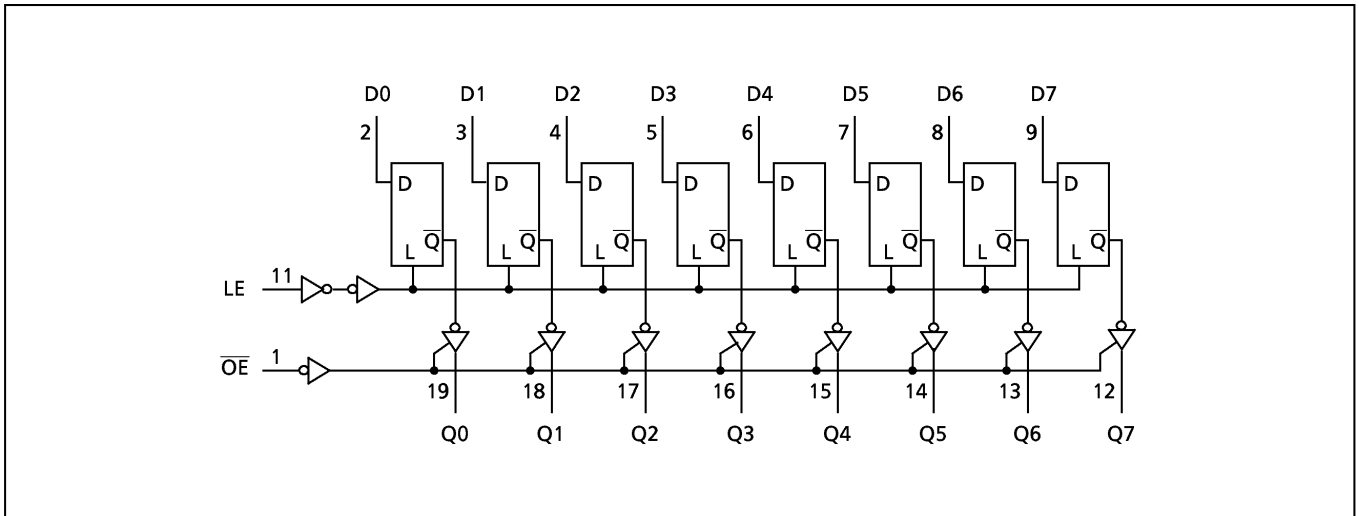
**IEC LOGIC SYMBOL**



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SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7.0	V
DC Input Voltage	$V_{IN}$	-0.5~7.0	V
DC Output Voltage	$V_{OUT}$	-0.5~7.0 (Note 1)	V
		-0.5~ $V_{CC} + 0.5$ (Note 2)	
Input Diode Current	$I_{IK}$	-20	mA
Output Diode Current	$I_{OK}$	±20 (Note 3)	mA
DC Output Current	$I_{OUT}$	±25	mA
DC Vcc/Ground Current	$I_{CC}$	±75	mA
Power Dissipation	$P_D$	180	mW
Storage Temperature	$T_{stg}$	-65~150	°C

(Note 1) Output in Off-State

(Note 2) High or Low State.  $I_{OUT}$  absolute maximum rating must be observed.

(Note 3)  $V_{OUT} < GND, V_{OUT} > V_{CC}$

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	4.5~5.5	V
Input Voltage	$V_{IN}$	0~5.5	V
Output Voltage	$V_{OUT}$	0~5.5 (Note 4)	V
		0~ $V_{CC}$ (Note 5)	
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	$dt/dV$	0~20	ns/V

(Note 4) Output in Off-State

(Note 5) High or Low State

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## DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITON	V <sub>CC</sub> (V)	Ta = 25°C			Ta = -40~85°C		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
High - Level Input Voltage	V <sub>IH</sub>		4.5~5.5	2.0	—	—	2.0	—	V	
Low - Level Input Voltage	V <sub>IL</sub>		4.5~5.5	—	—	0.8	—	0.8	V	
High - Level Output Voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50μA	4.5	4.40	4.50	—	4.40	—	V
			I <sub>OH</sub> = -8mA	4.5	3.94	—	—	3.80	—	
Low - Level Output Voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50μA	4.5	—	0.0	0.1	—	0.1	V
			I <sub>OL</sub> = 8mA	4.5	—	—	0.36	—	0.44	
3 - State Output Off - State Current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND	5.5	—	—	±0.25	—	±2.50	μA	
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5V or GND	0~5.5	—	—	±0.1	—	±1.0		
Quiescent Supply Current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	—	—	4.0	—	40.0		
	I <sub>CCT</sub>	PER INPUT : V <sub>IN</sub> = 3.4V OTHER INPUT : V <sub>CC</sub> or GND	5.5	—	—	1.35	—	1.50	mA	
Output Leakage Current	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5V	0	—	—	0.5	—	5.0	μA	

TIMING REQUIREMENTS ( Input t<sub>r</sub> = t<sub>f</sub> = 3ns )

PARAMETER	SYMBOL	TEST CONDITION	V <sub>CC</sub> (V)	Ta = 25°C		Ta = -40~85°C	UNIT
				TYP .	LIMIT	LIMIT	
Minimum Pulse Width (LE)	t <sub>W</sub> (H)		5.0 ± 0.5	—	6.5	8.5	ns
Minimum Set - up Time	t <sub>s</sub>		5.0 ± 0.5	—	1.5	1.5	
Minimum Hold Time	t <sub>h</sub>		5.0 ± 0.5	—	3.5	3.5	

AC ELECTRICAL CHARACTERISTICS ( Input  $t_r = t_f = 3\text{ns}$  )

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C			Ta = -40~85°C		UNIT	
			V <sub>CC</sub> (V)	CL (pF)	MIN.	TYP.	MAX.		MIN.
Propagation Delay Time (LE-Q)	$t_{pLH}$ $t_{pHL}$		5.0 ± 0.5	15	—	7.7	12.3	1.0	13.5
				50	—	8.5	13.3	1.0	14.5
Propagation Delay Time (D-Q)	$t_{pLH}$ $t_{pHL}$		5.0 ± 0.5	15	—	5.1	8.5	1.0	9.5
				50	—	5.9	9.5	1.0	10.5
3-State Output Enable Time	$t_{pZL}$ $t_{pZH}$	RL = 1kΩ	5.0 ± 0.5	15	—	6.3	10.9	1.0	12.5
				50	—	7.1	11.9	1.0	13.5
3-State Output Disable Time	$t_{pLZ}$ $t_{pHZ}$	RL = 1kΩ	5.0 ± 0.5	50	—	8.8	11.2	1.0	12.0
Output to Output Skew	$t_{oS LH}$ $t_{oS HL}$	(Note 6)	5.0 ± 0.5	50	—	—	1.0	—	1.0
Input Capacitance	C <sub>IN</sub>				—	4	10	—	10
Output Capacitance	C <sub>OUT</sub>				—	6	—	—	—
Power Dissipation Capacitance	C <sub>PD</sub>	(Note 7)			—	25	—	—	—

(Note 6) Parameter guaranteed by design.  $t_{oS LH} = |t_{pLH m} - t_{pLH n}|$ ,  $t_{oS HL} = |t_{pHL m} - t_{pHL n}|$

(Note 7) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 \text{ (per latch)}$$

And the total C<sub>PD</sub> when n pcs. of Latch operate can be gained by the following equation :

$$C_{PD} \text{ (total)} = 14 + 11 \cdot n$$

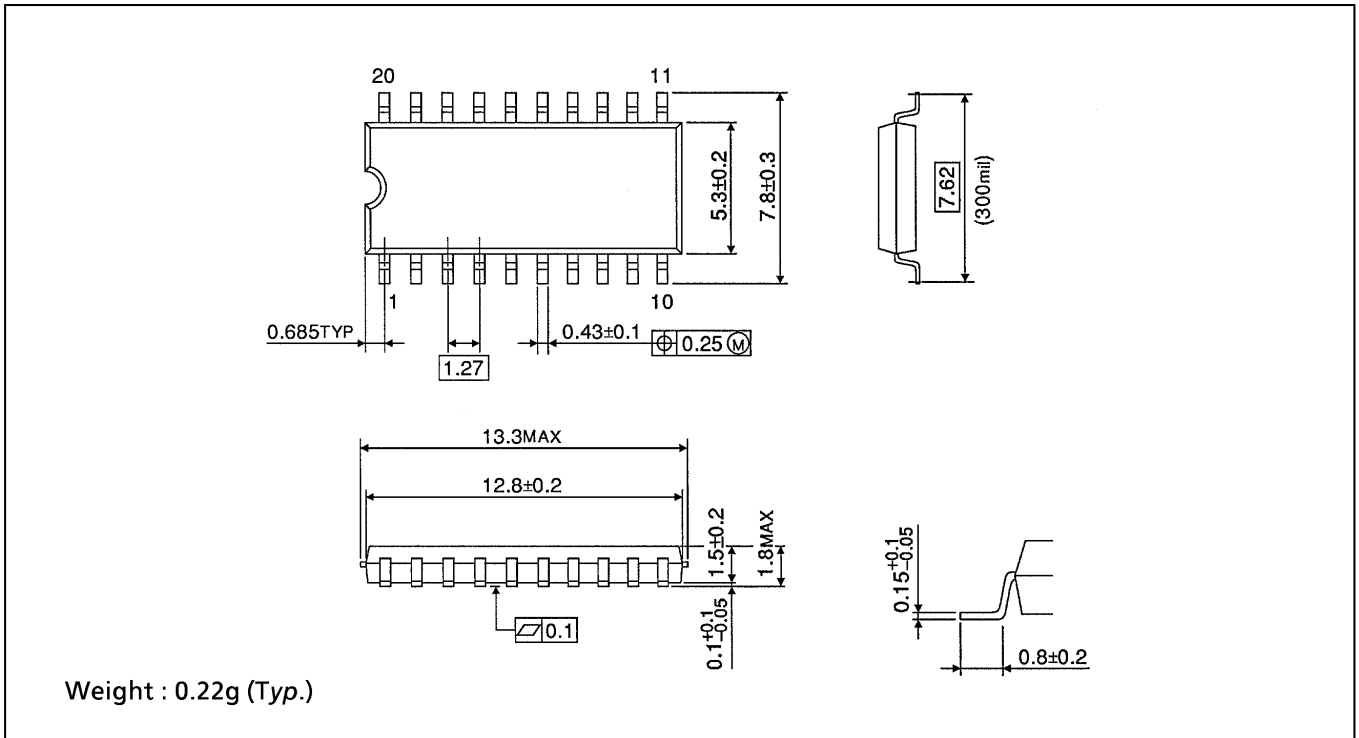
NOISE CHARACTERISTICS ( Input  $t_r = t_f = 3\text{ns}$  )

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C			UNIT
			V <sub>CC</sub> (V)	TYP.	MAX.	
Quiet Output Maximum Dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50pF	5.0	1.1 (1.2)	1.5 (1.6)	V
Quiet Output Minimum Dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50pF	5.0	-1.1 (-1.2)	-1.5 (-1.6)	V
Minimum High Level Dynamic Input Voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50pF	5.0	—	2.0	V
Maximum Low Level Dynamic Input Voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50pF	5.0	—	0.8	V

(Note) The value in ( ) only applies to JEDEC SOP (FW) devices.

SOP 20PIN (200mil BODY) OUTLINE DRAWING (SOP20-P-300-1.27)

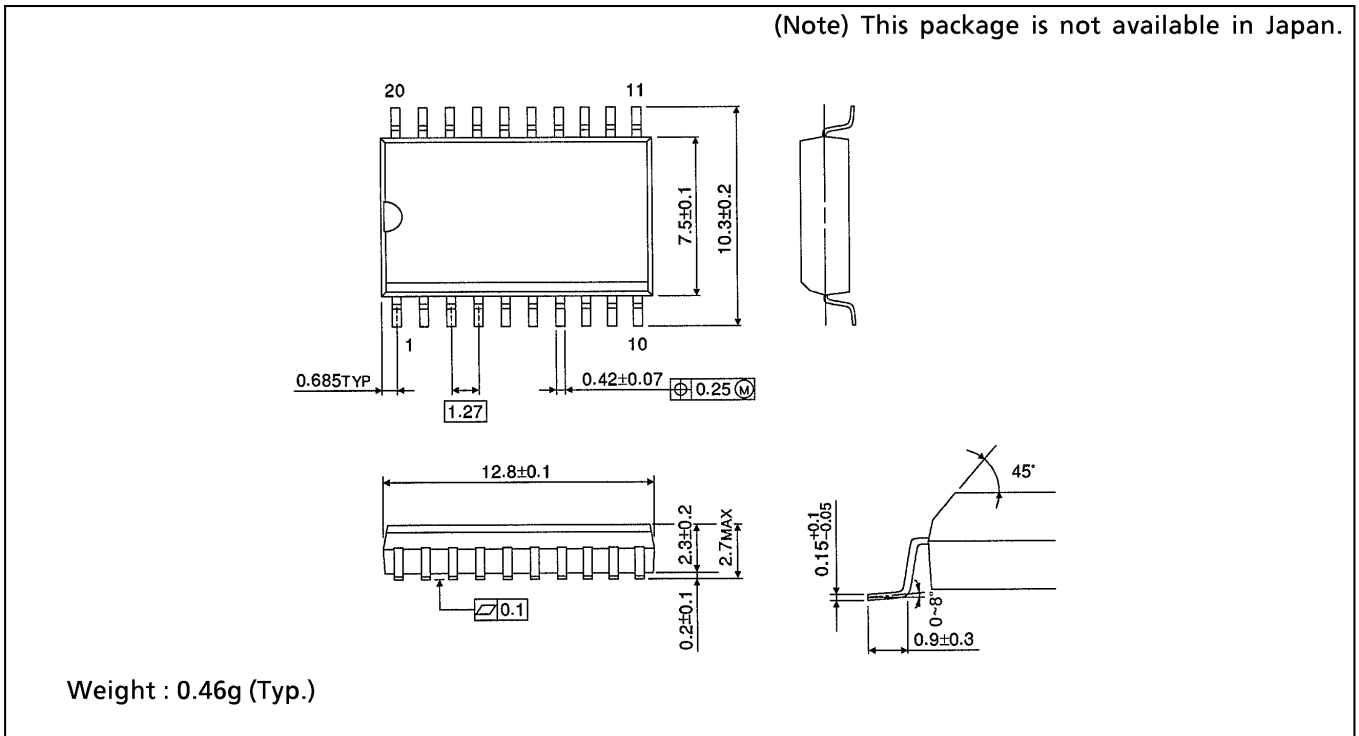
Unit in mm



SOP 20PIN (300mil BODY) OUTLINE DRAWING (SOP20-P-300-1.27)

Unit in mm

(Note) This package is not available in Japan.



**TSSOP 20PIN OUTLINE DRAWING (TSSOP20-P-0044-0.65)**

Unit in mm

